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Field Effect Transistor -N-Channel, Enhancement Mode

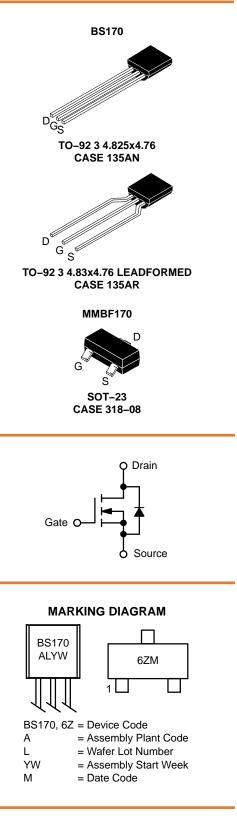
BS170, MMBF170

General Description

These N–Channel enhancement mode field effect transistors are produced using **onsemi**'s proprietary, high cell density, DMOS technology. These products have been designed to minimize on–state resistance while provide rugged, reliable, and fast switching performance. They can be used in most applications requiring up to 500 mA DC. These products are particularly suited for low voltage, low current applications such as small servo motor control, power MOSFET gate drivers, and other switching applications.

Features

- High Density Cell Design for Low R_{DS(ON)}
- Voltage Controlled Small Signal Switch
- Rugged and Reliable
- High Saturation Current Capability
- These are Pb–Free Devices



ORDERING INFORMATION

See detailed ordering and shipping information on page 6 of this data sheet.

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 6.

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

Symbol	Parameter		BS170	MMBF170	Unit
V _{DSS}	Drain-Source Voltage		60		V
V _{DGR}	Drain–Gate Voltage ($R_{GS} \le 1 M\Omega$)		60		V
V _{GSS}	Gate-Source Voltage		±20		V
Ι _D	Drain Current	- Continuous	500	500	mA
		- Pulsed	1200	800	
T _J , T _{STG}	Operating and Storage Temperature Range		– 55 to 150		°C
ΤL	Maximum Lead Temperature for Soldering Purposes, 1/16" from Case for 10 Seconds		30	00	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Symbol	Parameter	BS170	MMBF170	Unit
PD	Maximum Power Dissipation Derate above 25°C	830 6.6	300 2.4	mW mW/°C
R_{\thetaJA}	Thermal Resistance, Junction to Ambient	150	417	°C/W

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Symbol	Parameter	Test Condition	Туре	Min	Тур	Max	Unit
OFF CHA	RACTERISTICS						-
BV_{DSS}	Drain-Source Breakdown Voltage	V_{GS} = 0 V, I_D = 100 μ A	All	60	-	-	V
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V}$	All	Ι	-	0.5	μΑ
I _{GSSF}	Gate – Body Leakage, Forward	$V_{GS} = 15 \text{ V}, V_{DS} = 0 \text{ V}$	All	Ι	-	10	nA
ON CHAR	ACTERISTICS (Note 1)						-
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 1 \text{ mA}$	All	0.8	2.1	3	V
R _{DS(ON)}	Static Drain–Source On–Resistance	V_{GS} = 10 V, I _D = 200 mA	All	-	1.2	5	Ω
9 FS	Forward Transconductance	V_{DS} = 10 V, I_{D} = 200 mA	BS170	-	320	-	mS
		$V_{DS} \ge 2 V_{DS(on)}, I_D = 200 \text{ mA}$	MMBF170	-	320	-	
DYNAMIC	CHARACTERISTICS	•				•	
C _{iss}	Input Capacitance	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V},$	All	-	24	40	pF
C _{oss}	Output Capacitance	f = 1.0 MHz	All	-	17	30	pF
C _{rss}	Reverse Transfer Capacitance		All	-	7	10	pF
SWITCHIN	IG CHARACTERISTICS (Note 1)						-
t _{on}	Turn–On Time	$\begin{array}{l} V_{\text{DD}} = 25 \text{ V}, \ I_{\text{D}} = 200 \text{ mA}, \\ V_{\text{GS}} = 10 \text{ V}, \ R_{\text{GEN}} = 25 \ \Omega \end{array}$	BS170	-	-	10	ns
		$\label{eq:VDD} \begin{array}{l} V_{DD} = 25 \ V, \ I_{D} = 500 \ mA, \\ V_{GS} = 10 \ V, \ R_{GEN} = 50 \ \Omega \end{array}$	MMBF170	-	_	10	
t _{off}	Turn–Off Time	$\begin{array}{l} V_{\text{DD}} = 25 \text{ V}, \ I_{\text{D}} = 200 \text{ mA}, \\ V_{\text{GS}} = 10 \text{ V}, \ R_{\text{GEN}} = 25 \ \Omega \end{array}$	BS170	-	-	10	ns
		V_{DD} = 25 V, I _D = 500 mA, V _{GS} = 10 V, R _{GEN} = 50 Ω	MMBF170	_	-	10	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%.

TYPICAL ELECTRICAL CHARACTERISTICS

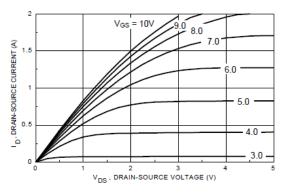


Figure 1. On–Region Characteristics

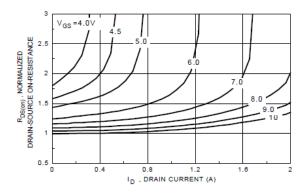
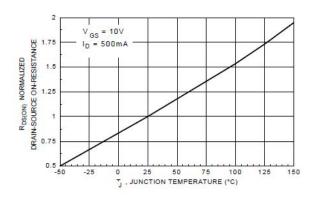
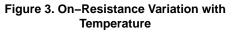


Figure 2. On–Resistance Variation with Gate Voltage and Drain Current





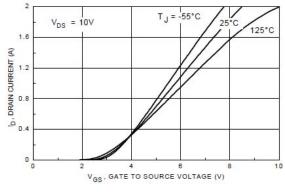


Figure 5. Transfer Characteristics

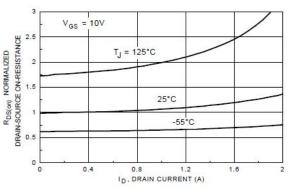


Figure 4. On–Resistance Variation with Drain Current and Temperature

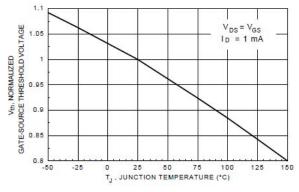


Figure 6. Gate Threshold Variation with Temperature

TYPICAL ELECTRICAL CHARACTERISTICS (continued)

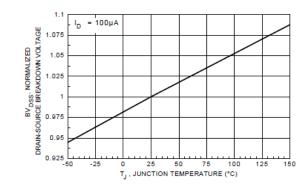


Figure 7. Breakdown Voltage Variation with Temperature

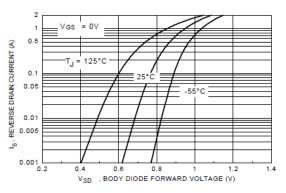


Figure 8. Body Diode Forward Voltage Variation with Current and Temperature

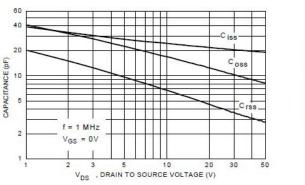


Figure 9. Capacitance Characteristics

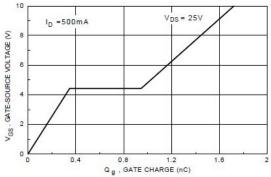


Figure 10. Gate Charge Characteristics

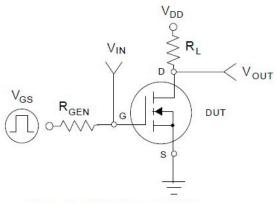


Figure 11. Switching Test Circuit

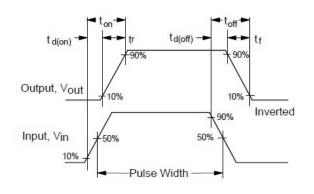


Figure 12. Switching Waveforms

TYPICAL ELECTRICAL CHARACTERISTICS (continued)

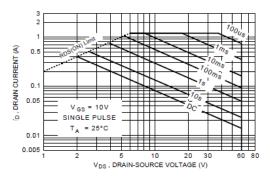


Figure 13. BS170 Maximum Safe Operating Area

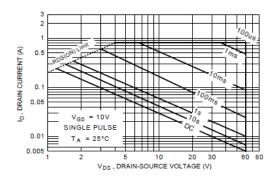


Figure 14. MMBF170 Maximum Safe Operating Area

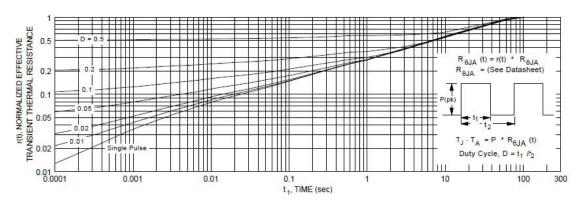


Figure 15. TO-92, BS170 Transient Thermal Response Curve

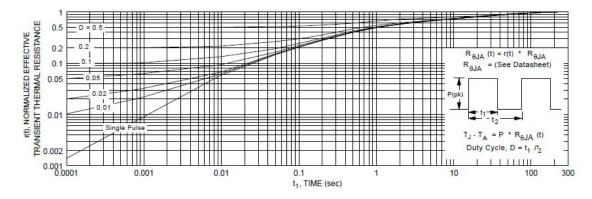


Figure 16. SOT-23, MMBF170 Transient Thermal Response Curve

ORDERING INFORMATION

Part Number	Package	Lead Frame	Pin Array	Shipping [†]
BS170	TO–92 (Pb–Free)	Straight	DGS	10000 Units / Bulk
BS170-D26Z	TO–92 (Pb–Free)	Forming	DGS	2000 / Tape & Reel
BS170-D27Z	TO–92 (Pb–Free)	Forming	DGS	2000 / Tape & Reel
BS170-D75Z	TO–92 (Pb–Free)	Forming	DGS	2000 / Ammo
MMBF170	SOT-23 (Pb-Free)			3000 / Tape & Reel

DISCONTINUED (Note 2)

BS170-D74Z	TO–92 (Pb–Free)	Forming	DGS	2000 / Ammo
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†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
2. DISCONTINUED: This device is not recommended for new design. Please contact your onsemi representative for information. The most

current information on this device may be available on www.onsemi.com.

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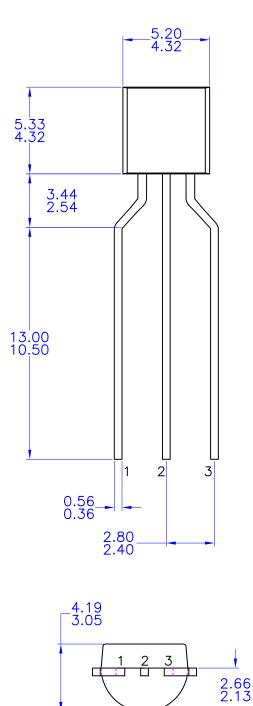
TO-92 3 4.825x4.76 CASE 135AN ISSUE O DATE 31 JUL 2016 _5.20_ ______ 5.33 (0.81) 15.62 2 3 1 0.52 0.56 0.36 1.27 NOTES: UNLESS OTHERWISE SPECIFIED 2.54 A) DRAWING WITH REFERENCE TO JEDEC TO-92 RECOMMENDATIONS. B) ALL DIMENSIONS ARE IN MILLIMETERS. с́э DRAWING CONFORMS TO ASME Y14.5M-2009. 4.19 3.05 2.66 2.13 2 3 1 Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. **DOCUMENT NUMBER:** 98AON13880G **DESCRIPTION:** TO-92 3 4.825X4.76 PAGE 1 OF 1

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SOT-23 (TO-236) 2.90x1.30x1.00 1.90P **CASE 318**

ISSUE AU

DATE 14 AUG 2024









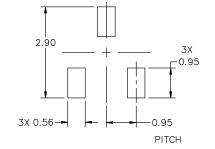




XXX = Specific Device Code М = Date Code

= Pb-Free Package .

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



MILLIMETERS						
DIM	MIN	NOM	МАХ			
А	0.89	1.00	1.11			
A1	0.01	0.06	0.10			
b	0.37	0.44	0.50			
с	0.08	0.14	0.20			
D	2.80	2.90	3.04			
E	1.20	1.30	1.40			
е	1.78	1.90	2.04			
L	0.30	0.43	0.55			
L1	0.35	0.54	0.69			
Ηe	2.10	2.40	2.64			
Т	0°		10°			

NOTES:

DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018. CONTROLLING DIMENSIONS: 1.

2. MILLIMETERS.

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BASE MATERIAL. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, 4. PROTRUSIONS, OR GATE BURRS.

RECOMMENDED MOUNTING FOOTPRINT

* For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

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DATE 14 AUG 2024

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE	I	
STYLE 9:	STYLE 10:	STYLE 11:	STYLE 12:	STYLE 13:	STYLE 14:
PIN 1. ANODE	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. SOURCE	PIN 1. CATHODE
2. ANODE	2. SOURCE	2. CATHODE	2. CATHODE	2. DRAIN	2. GATE
3. CATHODE	3. GATE	3. CATHODE-ANODE	3. ANODE	3. GATE	3. ANODE
STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:	STYLE 19:	STYLE 20:
PIN 1. GATE	PIN 1. ANODE	PIN 1. NO CONNECTION	PIN 1. NO CONNECTION	I PIN 1. CATHODE	PIN 1. CATHODE
2. CATHODE	2. CATHODE	2. ANODE	2. CATHODE	2. ANODE	2. ANODE
3. ANODE	3. CATHODE	3. CATHODE	3. ANODE	3. CATHODE-ANODE	3. GATE
STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:	STYLE 25:	STYLE 26:
PIN 1. GATE	PIN 1. RETURN	PIN 1. ANODE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE
2. SOURCE	2. OUTPUT	2. ANODE	2. DRAIN	2. CATHODE	2. ANODE
3. DRAIN	3. INPUT	3. CATHODE	3. SOURCE	3. GATE	3. NO CONNECTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE				

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